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DESCRIPTION

SWITCHED-CURRENT ANALOGUE-TO-DIGITAL CONVERTER

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The invention relates to a switched-current pipeline analogue-to-digital converter and an electronic device comprising such a converter.

10 The general architecture of a typical N -bit switched-current pipeline analogue-to-digital converter (ADC) is illustrated in Figure 1. It comprises an analogue current input 10 and N cascaded conversion stages $S_1...S_N$. Each stage generates one bit $b_1...b_N$ and, except for the last stage, an analogue residue current $r_1...r_{N-1}$ which is passed to the following stages for conversion.

15 De-skew logic 20 re-times the bits and provides bits $B_1...B_N$ simultaneously. The general architecture of each conversion stage S_i , except the last S_N , is illustrated in Figure 2 and comprises a sample-and-hold (S/H) circuit 30 for sampling the input current r_{i-1} , a current comparator 40 for generating one bit b_i by comparing the input current r_{i-1} with a reference threshold current, a

20 current digital-to-analogue converter (DAC) 50 for converting the bit b_i to a current, and a summing means 60 for generating the residue current r_i as the difference between the input current r_{i-1} , as delivered via the current memory 30, and the current delivered by the DAC 50, I_{DAC} . The last conversion stage S_N has only a current comparator 40, for providing b_N , as no residue is

25 required.

A fast conversion speed is required in electronic devices that process signals having a wide bandwidth. An example of such an electronic device is a wireless receiver in which a received signal is digitised before demodulation in a digital signal processor. Another example of such an electronic device is a

30 digital recorder that incorporates an ADC for converting an analogue signal to a digital signal prior to writing the digital signal to a recording medium. In order to achieve a fast conversion speed in an ADC it is desirable to use an

architecture that reduces the number of operating phases. The use of a two-phase clock enables the clock rate to be minimised, resulting in reduced power consumption or a higher conversion rate in electronic devices comprising an ADC.

5 US5,990, 820 discloses a switched-current pipeline ADC that uses two-phase operation. The S/H circuit 30 samples its input current on one phase and the current comparator 40 generates a bit b_i during the other phase. Therefore, this prior art ADC requires the input current r_{i-1} to each conversion stage S_i to be present on both phases. Consequently, the residue current r_i
 10 provided at the output of each conversion stage S_i must also be present on both phases. To enable the S/H circuit 30 to deliver current to the summing means 60 during the sampling phase, as well as during the holding phase, it includes a current mirror. However, a current mirror has a mismatch error which limits the precision of the conversion process. Therefore, a
 15 disadvantage of the two-phase ADC disclosed in US5,990,820 is the mismatch error resulting from the use of a current mirror in the S/H circuit 30.

In "A 10-bit Pipelined Switched-Current A-D Converter", D. Macq, IEEE Jnl of Solid-State Circuits, Aug. 1994, pp.967-971, the use of an algorithm for improving conversion accuracy is described, known as the Redundant Signed
 20 Digit (RSD) algorithm. The RSD algorithm requires at each conversion stage S_i the generation of, instead of a single bit b_i , two values p_i and q_i generated by comparing the input current r_{i-1} with two reference threshold currents $\pm I_{ref}$. There is, therefore, a threshold band of $2I_{ref}$ for the conversion stage. The pair of outputs, p_i and q_i , for the conversion stage S_i indicates whether the input
 25 current r_{i-1} is significantly positive ($p_i=1, q_i=0$), in which case I_{DAC} is subtracted from the input current r_{i-1} in the summing means 60, whether the input current r_{i-1} is significantly negative ($p_i=0, q_i=1$), in which case I_{DAC} is added to the input current r_{i-1} , or whether the input current r_{i-1} is neither significantly positive nor
 30 significantly negative ($p_i=0, q_i=0$), in which case nothing is added to or subtracted from the input current r_{i-1} . In this way the accuracy with which the the input current r_{i-1} polarity is determined can be relaxed and the errors this causes are corrected in digital correction logic. Figure 10 illustrates the

architecture of an N -bit switched-current pipeline ADC using an RSD algorithm. It is identical to the ADC illustrated in Figure 1, except that each conversion stage S_i generates digital outputs p_i and q_i and the de-skew logic 20' includes digital correction logic to generate the bit b_i from p_i and q_i . The architecture illustrated in Figure 10 is commonly referred to as a 1.5 bit/stage pipeline structure. However, the RSD algorithm is applicable only to the compensation of errors in the bit generation part of each conversion stage S_i , as performed by the current comparator 40, and is not applicable to the compensation of errors in the S/H circuit 30, so cannot be used to correct for the errors introduced by the current mirrors in the S/H circuit of the ADC architecture of US5,990, 820.

A known technique for increasing the conversion speed is to multiplex two or more pipelines of conversion stages, such that bits $b_1...b_N$ are produced sequentially from the different pipelines, thereby multiplying the conversion rate by the number of pipelines.

An object of the invention is to provide an improved switched-current pipeline analogue-to-digital converter and electronic device comprising such a converter.

According to a first aspect of the invention there is provided a current mode pipelined analogue-to-digital converter (ADC) comprising a plurality of serially connected conversion stages wherein at least one conversion stage comprises, a stage input for receiving a current for conversion, a sample-and-hold (S/H) circuit coupled to sample the current at the stage input during a first time period and to hold the sampled current during a second time period, the S/H circuit having first and second outputs, the first output delivering a mirror of the sampled current during the first time period and a mirror of the held current during the second time period and the second output delivering the held current directly during the second time period, a current comparator means having an input coupled to the first output of the S/H circuit for comparing a current at said input with one or more reference currents, a digital output coupled to an output of the current comparator means for producing a digital signal representing the

digital conversion performed by the stage, a digital-to-analogue converter (DAC) having an input coupled to the output of the current comparator means, and a summing means having a first input coupled to an output of the DAC, a second input coupled to the second output of the S/H circuit, and an output for delivering a residual current during the second time period.

The combined first and second time periods correspond to one clock period. The input current to the conversion stage defined by the invention need be present for only the first time period, while the S/H circuit is sampling. The residual current is provided only during the second time period when the S/H circuit is in its hold state and providing a direct, i.e. non-mirrored, current to the summing means 160, thereby avoiding the need to supply the summing means 160 from a current mirror, and therefore avoiding the inherent mismatch error of a current mirror. When such conversion stages are cascaded, the operation during the two time periods of adjacent stages is interchanged such that each stage provides a residual current to the following stage while that following stage is sampling.

Two or more pipelines of conversion stages may be operated with the sampling periods of corresponding stages of each pipeline multiplexed. In this way it is possible to implement an ADC with a higher conversion rate of two or more samples per clock period. The S/H circuit supplies a mirrored current to the current comparator means. Optionally a plurality of mirrored currents may be supplied to respective current comparator means. In this case the digital signal delivered at the output of each current comparator means is available for application of an RSD algorithm for improving conversion accuracy, and the DAC has a plurality of inputs each coupled to the output of a respective current comparator means.

According to a second aspect of the invention there is provided an electronic device comprising an ADC in accordance with the first aspect of the invention.

The invention will now be described, by way of example, with reference to the accompanying drawings wherein:

Figure 1 illustrates the general architecture of a 1 bit/stage N-bit switched-current pipeline ADC,

Figure 2 illustrates a prior art architecture of a conversion stage,

Figure 3 is a block schematic diagram of a first embodiment of a conversion stage in accordance with the invention,

Figure 4 is a schematic diagram of a S/H circuit,

Figure 5 is a timing diagram for the S/H circuit of Figure 4,

Figure 6 is a schematic diagram of a current comparator means comprising a regenerative circuit,

Figure 7 is a schematic diagram of a DAC,

Figure 8 is a block schematic diagram of a second embodiment of a conversion stage,

Figure 9 is a schematic diagram of a non-regenerative comparator means,

Figure 10 illustrates the general architecture of an N-bit switched-current pipeline ADC including an RSD algorithm,

Figure 11 is a block schematic diagram of a third embodiment of a conversion stage,

Figure 12 is a block schematic diagram of an ADC having two pipelines of conversion stages multiplexed,

Figure 13 is a block schematic diagram of an electronic device comprising an ADC,

Figure 14 is a table of the states of ADC elements, for an ADC comprising the conversion stage of Figure 3,

Figure 15 is a table of the states of ADC elements, for an ADC comprising the conversion stage of Figure 8,

Figure 16 is a table of the states of ADC elements, for an ADC comprising multiplexed pipelines and the conversion stage of Figure 3,

Figure 17 is a schematic diagram of a S/H circuit suitable for supplying two pipelines of conversion stages,

Figure 18 is a timing diagram for the S/H circuit of Figure 17,

Figure 19 is a schematic diagram of an alternative S/H circuit suitable for supplying two pipelines of conversion stages, and

Figure 20 is a timing diagram for the S/H circuit of Figure 19.

5 The invention uses the general ADC architecture illustrated in Figure 1 and described above, so this architecture will not be described again, but does not use the known general architecture of the conversion stage illustrated in Figure 2.

10 The first embodiment of a conversion stage S_i illustrated in Figure 3 comprises a current memory means 130. The current memory means 130 comprises a balanced class AB switched-current memory circuit. An input current, which is either the residue current r_{i-1} from the previous conversion stage or, in the case of the first conversion stage of the pipeline $S_1...S_N$, the initial current r_0 prior to any conversion, is coupled to a balanced input of the current memory means 130 by means of a first switch means 120. The first switch means 120 operates to couple the input current to the balanced input of the current memory means 130 during a sampling period Φ_S and to decouple the input current during a holding period Φ_H . The sampling period Φ_S alternates for alternate conversion stages S_i of the pipeline. For example the even numbered input currents $r_0, r_2, r_4...$ etc are coupled during a first clock phase Φ_1 of a two-phase clock and decoupled during a second clock phase Φ_2 , whereas the odd numbered input currents $r_1, r_3, r_5...$ etc are coupled during the second clock phase Φ_2 and decoupled during the first clock phase Φ_1 . The two clock phases Φ_1 and Φ_2 are non-overlapping.

25 The current memory means 130 comprises a direct output 131 and a mirror output 132, both outputs being balanced outputs. The direct output 131 is coupled to an input of a second switch means 135 which operates to couple the direct output 131 to an input of a summing means 160 during the holding period Φ_H and to decouple the direct output 131 from the summing means 160 during the sampling period Φ_S . The current present at the direct output 131 during the holding period Φ_H is a replica of the input current at the end of the

sampling period Φ_S . The current present at the mirror output 132 during the sampling period Φ_S is a replica of the input current and during the holding period Φ_H this value of the current is maintained. The combination of the current memory means 130, the first switch means 120 and the second switch means 135 constitutes a S/H circuit.

The mirror output 132 of the current memory means 130 is coupled to a differential input of a comparator means 140. The comparator means 140 is arranged to reset during the sampling period Φ_S , and during the holding period Φ_H regeneratively amplifies the current present at the mirror output 132. The direction of regeneration is determined by the polarity of the current present at the mirror output 132. The comparator means 140 has a pair of outputs which provide a quantised value D and the inverse \overline{D} . The D output of the comparator means 140 is coupled to the input of a D-type flip-flop 145 which is clocked on the rising edge of the holding period $\overline{\Phi'_H}$ and provides on an output a value of bit b_i from the conversion stage. The D and \overline{D} outputs of the comparator means 140 are coupled to respective inputs of a digital-to-analogue converter (DAC) 150 which converts the quantised value D to a bit current. The bit current is coupled to the summing means 160 by means of a third switch means 155 which operates to couple the bit current to the summing means during the holding period Φ_H and to decouple the bit current from the summing means during the sampling period Φ_S .

The summing means 160 is arranged to form, during the holding period Φ_H , the difference between the bit current and the current at the direct output 131, thereby providing on an output from the conversion stage S_i the residue r_i .

Figure 4 illustrates a S/H circuit comprising the current memory means 130, the first switch means 120 and the second switch means 135. The current memory means 130 comprises first and second complementary PMOS/NMOS transistor pairs P_1/N_1 and P_2/N_2 each pair forming, in conjunction with respective switch means 133 and 134, a single ended class AB current memory cell, and together forming a balanced class AB current memory cell. An input current is stored in the balanced memory cell during a period Φ'_S

when third and fourth switch means 133 and 134 are closed, which occurs during the sampling period Φ_S , and the stored current is provided on the direct output 131 during the holding period Φ_H when the switch means 133 and 134 are open. The current memory means 130 also comprises third and fourth
 5 complementary PMOS/NMOS transistor pairs P_3/N_3 and P_4/N_4 coupled to provide a mirror on the mirror output 132 of the current in the balanced class AB current memory cell. As stated above, the current present at the mirror output 132 during the sampling period Φ_S is a replica of the input current, and during the holding period Φ_H this value of the current is maintained. All
 10 switches in the embodiments described in the present specification may be implemented as MOS transistors.

The timing relationship between Φ_S , Φ'_S and Φ_H is illustrated in Figure 5, a high level corresponding to closed switch means. The duration of the rising and falling edges of the switching transitions is exaggerated to
 15 demonstrated that the sampling during period Φ'_S terminates slightly before the input current is decoupled by the first switch means 120 at the end of period Φ_S , to ensure that the stored current is not distorted by the decoupling action.

Referring to Figure 6, the comparator means 140 comprises a
 20 regenerative comparator circuit 141 and a decoupling means 142. The regenerative comparator circuit 141 comprises two transconductors connected in a positive feedback loop, having complementary PMOS/NMOS transistor pairs P_5/N_5 and P_6/N_6 giving transconductances G_m , and a reset switch 144 which is closed during the sampling period Φ_S and has on-resistance R_{on} .
 25 When the reset switch 144 is closed, and with an input current I_{in} flowing at the input 143 of the comparator circuit 141, the voltage across the reset switch 144

is $\frac{I_{in}}{\frac{1}{R_{on}} - \frac{G_m}{2}}$. The loop is stable provided $R_{on} \leq \frac{2}{G_m}$. When the reset switch

144 is closed the regenerative comparator circuit 141 is reset, i.e. all memory of the comparator's previous state is removed. When the reset switch 144 is

opened, the condition for stability no longer holds and the voltage across the reset switch 144 is amplified regeneratively in a direction determined by its initial polarity until it reaches the supply rail voltages V_{ss} and V_{dd} . The speed of regeneration is dependent on the size of the input current I_{in} . Small input
 5 currents produce slow regeneration and large input currents produce rapid regeneration. The regeneration process can result in the phenomenon termed "kickback" which can limit the accuracy of the conversion process. Kickback would occur if large voltage swings at either side of the reset switch 144 are allowed to be transmitted back to the mirror output 132 of the current memory
 10 means 130, thereby corrupting the signal. The purpose of the decoupling means 142 is to prevent such kickback.

The decoupling means 142 comprises decoupling switches 145, 146 for decoupling from the regenerative comparator circuit 141 signals received from the mirror output 132, and also comprises a bypass switch 147 for providing a
 15 current path when the regenerative comparator circuit 141 is decoupled from the mirror output 132.

The decoupling means 142 is arranged to monitor the degree of regeneration and to open the decoupling switches 145, 146 when the degree of regeneration reaches a predetermined value, as follows. Gate means 148,
 20 providing a NOR function, has first and second gate inputs coupled to, respectively, either side of the reset switch 144 by means of respective first and second capacitors C_a and C_b . The first and second gate inputs are also coupled to a voltage reference source V_{ref} by means of reference switch means 149. The reference switch means 149 couples the first and second
 25 gate inputs to the voltage reference source V_{ref} throughout the sampling period Φ_S , when the reset switch 144 is also closed, and decouples them throughout the holding period Φ_H during which the regenerative comparator circuit 141 regenerates. The voltage of the voltage reference source V_{ref} is below the switching threshold of the gate means 148.

30 In operation, during the sampling period Φ_S the first and second gate inputs are forced to voltage V_{ref} and the first and second capacitors C_a and C_b charge to the difference voltages between V_{ref} and the voltages either side of

the reset switch 144. Because V_{ref} is below the switching threshold of the gate means 148, the gate provides a logical high level output which is arranged to maintain the decoupling switches 145, 146 closed and the bypass switch 147 open. At the start of the holding period Φ_H the reference switch means 149
 5 decouples the first and second gate inputs from the voltage reference source V_{ref} , but instantaneously the voltages at the first and second gate inputs are held at voltage V_{ref} by the charge on the first and second capacitors C_a and C_b . As regeneration ensues, the voltages either side of the reset switch 144 move towards the supply rail voltages, one to V_{ss} and the other to V_{dd} , depending on
 10 the polarity of the current at the mirror output 132, and these voltage changes are transmitted to, respectively, the first and second gate inputs via, respectively, the first and second capacitors C_a and C_b . When the voltage at either the first or second gate input goes above the switching threshold of the gate means 148, the voltage at the gate output goes to a logical low level,
 15 thereby causing the decoupling switches 145, 146 to decouple the mirror output 132 from the regenerative comparator circuit 141 and the bypass switch 147 to close, thereby providing a current path for the signal at the mirror output 132. In this way, the direction of regeneration is established reliably but the current memory means 130 is isolated before regeneration has reached
 20 damaging proportions. Output voltages for the quantised value D and the inverse \bar{D} are provided from the voltage either side of the reset switch 144.

Direct coupling of the current memory means 130 to the comparator means 140 is only possible because of the absence of kickback as described above. If comparator means 140 did not have the means to prevent kickback,
 25 kickback could occur during the holding period and the signals at the direct output 131 and the mirror output 132 of the current memory means 130 would have been corrupted, resulting in corruption of the quantised value D , and consequently corruption of the residue r_i .

Referring to Figure 7, the DAC 150 is a balanced current-mode 1-bit
 30 device. It comprises means for creating two DC currents of equal value but opposite polarity, $\pm I_{DAC}$ which are coupled to a balanced output 151 by means of a reversing switch arrangement 152 controlled by the quantised values D

and \overline{D} provided by the outputs of the comparator means 140. The reversing switch arrangement 152 enables the two DC currents $\pm I_{DAC}$ at the balanced output 151 to be reversed. The value of the two DC currents $\pm I_{DAC}$ is halved for each successive conversion stage S_i of the ADC. This allows the summing means 160 to be implemented using simple wired connections and without the need to double the residue.

The table of Figure 14 summarises the states of the ADC elements for each phase, Φ_1, Φ_2 , of a two-phase clock and for odd and even conversion stages S_i , for an ADC comprising the conversion stage of Figure 3. For odd numbered conversion stage S_i $i=1, 3, \dots$ etc, during the first clock phase Φ_1 the current memory means 130 is sampling, the comparator means 140 is resetting and the DAC 150 is OFF, meaning that it is decoupled from the summing means 160 by the third switch means 155. For even numbered conversion stage S_i $i=2, 4, \dots$ etc, during the first clock phase Φ_1 the current memory means 130 is holding, the comparator means 140 is quantising the current at the mirror output 132 and the DAC 150 is ON, meaning that it is coupled to the summing means 160 by the third switch means 155. During the second clock phase Φ_2 the status of the odd and even conversion stages are interchanged.

A second embodiment of a conversion stage S_i is illustrated in Figure 8. This second embodiment uses a non-regenerative circuit for the comparator means as an alternative way to avoid the generation of kickback. This non-regenerative comparator means is denoted by reference numeral 140' in Figure 8. Elements which are identical in Figure 3 and Figure 8 have the same reference numeral and will not be described again; only the differences are described, as follows. In Figure 8, the D-type flip-flop 145' is coupled between the non-regenerative comparator means 140' and the DAC 150 in order to latch the signal at the output of the non-regenerative comparator means 140', and outputs of D-type flip-flop 145' provide the quantised value D and its inverse \overline{D} to the DAC 150. The non-regenerative comparator means 140' has a low input impedance which protects the current memory means 130 from

kickback from the D-type flip-flop 145'. Referring to Figure 9, the non-regenerative comparator means 140' is a balanced circuit comprising voltage gain stages M_3/M_4 with source-follower feedback M_1/M_2 to provide a low input impedance.

5 The table of Figure 15 summarises the states of the ADC elements for each phase, Φ_1, Φ_2 , of a two-phase clock and for odd and even conversion stages S_i , for an ADC comprising the conversion stage of Figure 8. For odd numbered conversion stage S_i $i=1, 3, \dots$ etc, during the first clock phase Φ_1 the current memory means 130 is sampling, the comparator means 140' is
10 quantising the current at the mirror output 132 and the DAC 150 is OFF. For even numbered conversion stage S_i $i=2, 4, \dots$ etc, during the first clock phase Φ_1 the current memory means 130 is holding, the comparator means 140' is resetting and the DAC 150 is ON. During the second clock phase Φ_2 the status of the odd and even conversion stages are interchanged.

15 A third embodiment of a conversion stage S_i which generates values for p_i and q_i for use in an RSD algorithm is illustrated in Figure 11. Elements which are identical in Figure 3 and Figure 11 have the same reference numeral and will not be described again; only those elements that differ are described below. In Figure 11, the current memory means 230 comprises a direct output
20 131 and a first mirror output 132, the same as the current memory means 130, but in addition comprises a second current mirror and second mirror output 232. Both the first and second mirror outputs 132, 232 are balanced. The current present at the second mirror output 232 during the sampling period Φ_S is a replica of the input current, and during the holding period Φ_H this value of
25 the current is maintained. The first and second mirror outputs 132, 232 are coupled to, respectively, first and second comparator means 140, 140" which are identical. Current sources 241, 242 coupled to the first mirror output 132 thereby setting the switching threshold of the first comparator means 140 to $+I_{ref}$ and current sources 341, 342 coupled to the second mirror output 232 set
30 the switching threshold of the second comparator means 140" to $-I_{ref}$. An output from each of the first and second comparator means 140, 140" is

coupled to an input of respective D-type flip-flops 145 which provide on respective outputs a value for p_i and q_i . The output from each of the first and second comparator means 140, 140" is also coupled to respective inputs of a digital-to-analogue converter (DAC) 150' which converts to a DC current the quantised values D_p , D_q output from the first and second comparator means 140, 140" respectively. The values of the DAC output current and of I_{ref} are halved in successive conversion stages. In the present embodiment, the quantised values D_p , D_q can take one of three combinations, [0,0], [0,1] or [1,0], therefore the DAC 150' can be considered as a $1\frac{1}{2}$ -bit DAC. The DAC 150' in the embodiment of Figure 11 can use the same circuit as the DAC 150 in the embodiments of Figure 3 and 8 with D_p being equivalent to D and D_q being equivalent to \overline{D} .

Optionally, the conversion stage illustrated in Figure 11 which generates values for p_i and q_i may comprise two non-regenerative comparator means 140' instead of regenerative comparator means 140, 140", in which case the two D-type flip-flops 145 are coupled between the respective regenerative comparator means 140, 140" and the DAC 150, in the same manner as the conversion stage of Figure 8.

Referring to Figure 12, two pipelines of conversion stages can be multiplexed to form an ADC capable of operating at twice the conversion rate of a single pipeline. A first pipeline of conversion stages S'_i , $i=1,N$ operates to sample in odd numbered stages during a first phase Φ_1 of a two-phase clock and the even numbered stages sample during a second phase Φ_2 of the two-phase clock, and a second pipeline of conversion stages S''_i , $i=1,N$ operates to sample in odd numbered stages during the second phase Φ_2 of the two-phase clock and the even numbered stages sample during the first phase Φ_1 of the two-phase clock. Therefore, the initial current r_0 is sampled twice in each clock cycle. An initial S/H stage 11 samples the initial current r_0 and supplies the sampled current alternately to each pipeline. The table of Figure 16 summarises the states of the ADC elements for each phase, Φ_1, Φ_2 , of a two-phase clock and for odd and even conversion stages S_i , for the ADC of Figure

12 having two multiplex pipelines and comprising the conversion stage of Figure 3. Alternatively, the ADC of Figure 12 may comprise the conversion stage of Figure 8.

Figure 17 illustrates a S/H circuit suitable for use as the initial S/H stage
 5 11. It employs first and second class-A switched current memory cells M_1 and M_2 which are operated in a time-division multiplex regime, taking two samples in each clock cycle. On phase Φ_1 the initial current r_0 sums with bias current J and the current $J+r_0$ is sampled by the first memory cell M_1 . Simultaneously, the current r'_0 held in the second memory cell M_2 flows to the first pipeline of
 10 conversion stages S'_i , $i=1,N$. On phase Φ_2 , the second memory cell M_2 samples the initial current r_0 while the current r''_0 held in the first memory cell M_1 flows to the second pipeline of conversion stages S''_i , $i=1,N$. When the S/H circuit in Figure 17 is used to supply a non-multiplexed output current, the currents r'_0 and r''_0 can be summed to form a single output current i_o , as
 15 indicated by the dotted line in Figure 17. In practice, all the switches in Figure 17 are MOS transistors (normally NMOST's) which are turned on and off by the clock waveforms. The sampling instants are defined by the falling edges of the Φ'_1 and Φ'_2 clock waveforms illustrated in Figure 18. The memory switches operated by clock waveforms Φ'_1 and Φ'_2 are opened before the initial current
 20 r_0 is interrupted by Φ_1 and Φ_2 respectively. Any difference in the timing or shape of the falling edges of Φ'_1 and Φ'_2 will produce a sampling error and this can produce spurious frequencies in the output currents r'_0 and r''_0 . Further errors can result from an inadequate memory bandwidth. On the input phase of each memory cell M_1 , M_2 , the drain current of the memory cell's transistor
 25 attempts to follow the initial current r_0 but with an inevitable lag. In such class-A memory cells the transconductance is signal dependent because of the MOST's square-law behaviour in saturation and this makes the lag signal-dependent and the sampling errors that result can produce distortion. As an alternative to using the class-A switched current memory cells M_1 , M_2 , class-
 30 AB switched current memory cells, such as those described in relation to Figure 4, can be used in the S/H circuit of Figure 17.

Figure 19 illustrates an alternative S/H circuit suitable for use as the initial S/H stage 11, but which overcomes the disadvantages of the S/H circuit of Figure 17. It comprises a time-multiplexed pair of class-AB memory cells M_3 and M_4 , each with a different memory switch arrangement. The operation is the same as described above for the S/H circuit of Figure 17, except that clock phases Φ'_1 and Φ'_2 are replaced by a double frequency clock Φ_0 and its inverse $\overline{\Phi_0}$. This memory switch combination ensures that the memory cell M_3 tracks the initial current r_0 when the Φ_0 and Φ_1 switches within the memory cell M_3 are closed and memory cell M_4 tracks the initial current r_0 when the Φ_0 and Φ_2 switches within the memory cell M_4 are closed. In each case the sampling instant is determined by the falling edge of the Φ_0 clock and the clock mismatch problem is avoided. An input switch 12 closing on phase $\overline{\Phi_0}$ ensures a continuous path for the initial current r_0 during the time intervals in the sampling phases when the input paths to both memory cells M_3 and M_4 are interrupted. $\overline{\Phi_0}$ is generated from Φ_0 by means of an inverter which introduces a short delay, and consequently safeguards against premature interruption of the initial current r_0 . The use of class-AB, rather than class-A, memory cells reduces signal dependent errors. This arises because, unlike the class-A cell, the PMOS/NMOS pairs maintain a near signal-independent transconductance. Consequently, the class-AB memory cells M_3 , M_4 with finite bandwidths track the initial current r_0 with a fairly constant time lag over large signal amplitude variations and so causes less distortion. Furthermore, the charge injection which occurs when the memory switches open produce a nearly constant gain error which again results in little distortion. When the S/H circuit in Figure 19 is used to supply a non-multiplexed output current, the currents r'_0 and r''_0 can be summed to form a single output current i_o , as indicated by the dotted line in Figure 19.

Optionally the ADC of Figure 12 having two multiplex pipelines may comprise the means for generating p_i and q_i as described above for use in an RSD algorithm.

Optionally more than two pipelines may be multiplexed, and these may each comprise the means for generating p_i and q_i .

Optionally, the conversion stage described with reference to Figure 11 can have more than the two mirror outputs 132, 133 to enable more than two
5 quantisation levels to be implemented, and in this case the DAC 150' would be correspondingly modified to accommodate the increased number of quantisation levels. The RSD algorithm may be extended to accommodate more than two quantisation levels.

Optionally alternative configurations of circuit may be used for the
10 current memory means 130.

Optionally alternative configurations of circuit may be used for the DAC 150 or 150'.

Optionally each conversion stage may generate n bits by employing a comparator means 140, 140', 140'' having an appropriate number of
15 quantisation levels and a DAC 150, 150' capable of converting n bits.

Optionally the ADC and its constituent elements may comprise single-ended circuits instead of the balanced circuits described above.

Referring to Figure 13, a wireless receiver comprising an ADC in accordance with the invention comprises a signal input 500 for receiving a RF
20 signal from an antenna 490. The signal input 500 is coupled to an input of an RF filter 510 for filtering out signals in unwanted frequency bands. An output of the RF filter 510 is coupled to a low noise amplifier (LNA) 520 for amplifying the filtered signal. An output of the LNA 520 is coupled to a first input of first and second mixers 530, 540 for down-conversion. A second input of the first
25 mixer 530 is coupled to a local oscillator source 550 and a second input of the second mixer 540 is coupled to the local oscillator source 550 via a 90° phase shifting network 560. The first and second mixers 530, 540 provide on respective outputs in-phase and quadrature-phase down converted signals I , Q , and these outputs are coupled to respective inputs of anti-alias filters 570.
30 The anti-alias filters 570 provide filtered I and Q signals on respective outputs which are coupled to respective ADCs 580, 590 for digitisation of the filtered I and Q signals. The ADCs 580, 590 are in accordance with the first aspect of

the invention. An output from each ADC 580, 590, providing respectively digitised I and Q signals, is coupled to a digital signal processor 600 which applies channel filtering, demodulates the digitised I and Q signals and delivers data on an output 610.

5 In the present specification and claims the word "a" or "an" preceding an element does not exclude the presence of a plurality of such elements. Further, the word "comprising" does not exclude the presence of other elements than those listed.

10 From reading the present disclosure, other modifications will be apparent to persons skilled in the art. Such modifications may involve other features which are already known in the design, manufacture and use of analogue-to-digital converters, wireless receivers or switched-current circuits, and which may be used instead of or in addition to features already described herein.

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